

In the Specification:

Please amend the specification as follows:

Page 6, after the second paragraph insert:

The boron concentration may be less than  $5 \times 10^{14} \text{ cm}^{-3}$  and the concentration of transition metals impurities less than  $5 \times 10^{14} \text{ cm}^{-3}$ . The boron concentration may be less than  $5 \times 10^{15} \text{ cm}^{-3}$  and the concentration of transition metals impurities less than  $10^{13}$ . The crystal, after growth, may be annealed to above  $700^{\circ}\text{C}$ .